

















■ Features

- · 3"x2" compact size
- Medical safety approved (2 x MOPP) accroding to ANSI/AAMI ES60601-1 and IEC/EN60601-1
- Suitable for BF application with appropriate system consideration
- · Cooling by free air convection
- EMI class B for class

 configuration
- No load power consumption<0.1W
- Extremely low leakage current
- Protections: Short circuit / Overload / Over voltage

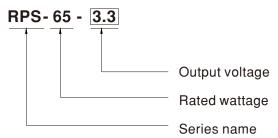
Applications

- Oral irrigator
- Hemodialysis machine
- · Medical computer monitors
- · Sleep apnea devices

Description

RPS-65 is a 65W highly reliable green PCB type medical power supply with a high power density on the 3" by 2" footprint. It accepts $80\sim264$ VAC input and offers various output voltages between 3.3V and 48V. The working efficiency is up to 91% and the extremely low no load power consumption is down below 0.1W. RPS-65 is able to be used for Class II (no FG) system design. The extremely low leakage current is less than $100\,\mu$ A. In addition, it conforms to international medical regulations (2*MOPP) and EMC EN55011, perfectly fitting all kinds of BF rated "patient contact" medical system equipment.

■ Model Encoding





65W Reliable Green Medical Power Supply

SPECIFICATION

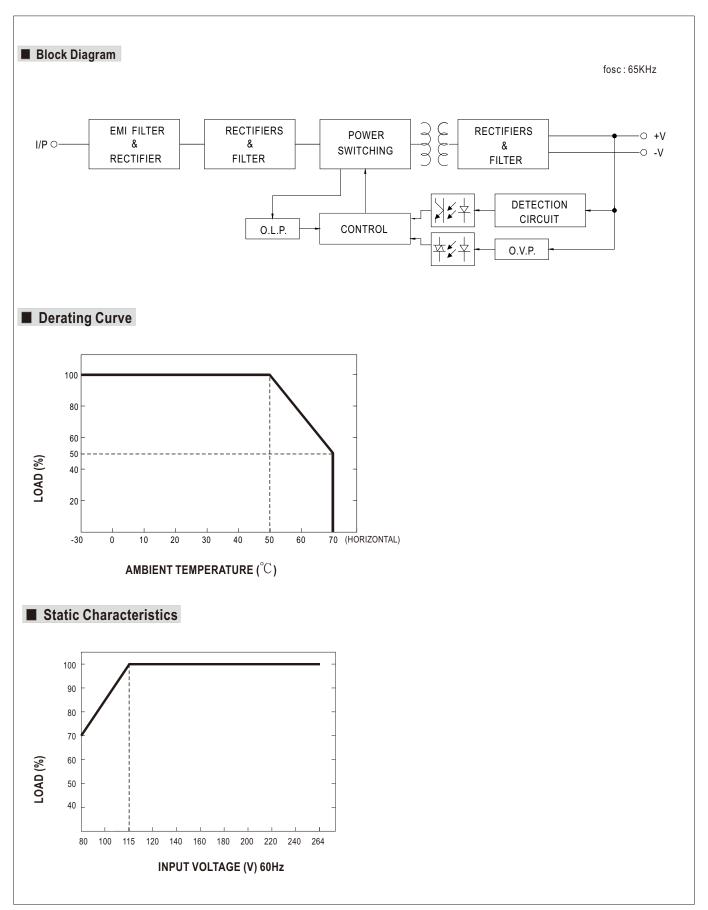
		RPS-65-3.3	RPS-65-5	RPS-65-7.5	RPS-65-12	RPS-65-15	RPS-65-24	RPS-65-48	
	DC VOLTAGE	3.3V	5V	7.5V	12V	15V	24V	48V	
OUTPUT	RATED CURRENT	10A	10A	8A	5.42A	4.34A	2.71A	1.36A	
	CURRENT RANGE	0 ~ 11A	0 ~ 11A	0 ~ 8.8A	0 ~ 5.96A	0 ~ 4.77A	0 ~ 2.98A	0 ~ 1.49A	
	RATED POWER	33W	50W	60W	65W	65.1W	65W	65.3W	
	PEAK LOAD(10sec.)	36.3W	55W	66W	71.5W	71.6W	71.5W	71.5W	
	RIPPLE & NOISE (max.) Note.2	80mVp-p	80mVp-p	80mVp-p	120mVp-p	120mVp-p	120mVp-p	150mVp-p	
	VOLTAGE ADJ.RANGE	2.9~3.6V	4.7~5.5V	7.12~8.3V	11.4~13.2V	13.5~16.5V	22.8~27.6V	45.6~52.8	
	VOLTAGE TOLERANCE Note.3		±2.0%	±2.0%	±2.0%	±1.0%	±1.0%	±1.0%	
	LINE REGULATION	±0.5%	±0.5%	±0.5%	±0.5%	±0.5%	士0.5%	±0.5%	
	LOAD REGULATION	±2.0%	±2.0%	±2.0%	±2.0%	±1.0%	±1.0%	±1.0%	
	SETUP, RISE TIME	500ms, 30ms / 230VAC 500ms, 30ms / 115VAC at full load							
	HOLD UP TIME (Typ.)	30ms / 230VAC 12ms / 115VAC at full load							
		80 ~ 264VAC 12ms / 115VAC at tuli load							
	FREQUENCY RANGE	00 ~ 204 VAC 47 ~ 63Hz							
PUT	EFFICIENCY (Typ.)	80%	84%	85%	88%	89%	90%	91%	
	AC CURRENT (Typ.)	1.5A / 115VAC	1A / 230VAC	0070	0070	0070	3070	3170	
	INRUSH CURRENT (Typ.)								
	LEAKAGE CURRENT(max.) Note.5	COLD STAR 30A/115VAC 50A/230VAC							
	LEARAGE CURRENT (IIIax.) Note.5								
	OVERLOAD	115 ~ 150% rate		avara avtamaticalli	. often feelt conditi	ian ia ramawad			
DOTECTION			1	overs automatically			07.0.00.41/	FF 0 04 0V	
ROTECTION	OVER VOLTAGE	3.8~4.5V	5.7~6.8V	8.6~11.3V	13.8~16.2V	17.2~20.3V	27.6~32.4V	55.2~64.8\	
				tage, re-power on t	o recover				
	WORKING TEMP.	,	fer to "Derating Cur	ve")					
	WORKING HUMIDITY	20% ~ 90% RH r							
IVIRONMENT	STORAGE TEMP., HUMIDITY	$-40 \sim +85^{\circ}$ C, $10 \sim 95\%$ RH non-condensing							
	TEMP. COEFFICIENT	±0.03% / °C (0~50°C)							
	VIBRATION	10 ~ 500Hz, 2G 10min./1cycle, period for 60min. each along X, Y, Z axes							
	OPERATING ALTITUDE Note.6	4000 meters							
		IEC60601-1, TUV EN60601-1, UL ANSI / AAMI ES60601-1 (3.1 version), CAN/CSA-C22.2 No. 60601-1:14 - Edition 3 approve Design refer to EN60335-1							
	SAFETY STANDARDS			ANSI/AAMI ES606		,CAN/CSA-C22		паноно аррго	
	SAFETY STANDARDS ISOLATION LEVEL		EN60335-1	ANSI/AAMI ES606	0.1 Ve131011)	,CAN/CSA-C22		ашон о аррго	
		Design refer to I	EN60335-1	ANSI/AAMI ES606	0.1 (6.1)	,CAN/CSA-C22		иноп о иррго	
	ISOLATION LEVEL	Design refer to I Primary-Second I/P-O/P: 4KVAC	EN60335-1		(0.1 Version)	,0AN/05A-022		аноп о аррго	
	ISOLATION LEVEL WITHSTAND VOLTAGE	Design refer to I Primary-Second I/P-O/P: 4KVAC	EN60335-1 ary: 2xMOPP		(3.1 Version)		est Level / Note	имоно иррго	
	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emis	EN60335-1 ary: 2xMOPP hms / 500VDC / 25° sion	C / 70% RH Standard EN55011 (C	CISPR11)	T. C	est Level / Note	инопо прри	
	ISOLATION LEVEL WITHSTAND VOLTAGE	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi	EN60335-1 ary: 2xMOPP nms / 500VDC / 25° sion on	C / 70% RH Standard EN55011 (C	CISPR11) CISPR11)	T C C	est Level / Note lass B lass B	иноп о цррго	
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MC	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter	EN60335-1 ary: 2xMOPP nms / 500VDC / 25° sion on	C/70% RH Standard EN55011 (C EN61000-3 EN61000-3	CISPR11) CISPR11) -2 -3	T C C C C C C C C T T	est Level / Note lass B lass B lass A		
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MC	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter	EN60335-1 ary: 2xMOPP nms / 500VDC / 25° sion on nt	C/70% RH Standard EN55011 (C EN61000-3 EN61000-3	CISPR11) CISPR11) -2 -3	T. C.	est Level / Note lass B lass B est Level / Note	14, 8KV contac ~2.7GHz)	
МС	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE EMC EMISSION	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4	CISPR11) CISPR11) -2 -3 -2 -3	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz	14, 8KV contac ~2.7GHz)	
МС	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts Surge susceptit	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4 EN61000-4	CISPR11) CISPR11) -2 -3 -2 -3 -4	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz able 9, 9~28V/m(385Me evel 3, 2KV/Line-Line	14, 8KV contac ~2.7GHz)	
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AFETY & MC Note. 7)	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE EMC EMISSION	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts Surge susceptit	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility polity peptibility	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4 EN61000-4	CISPR11) CISPR11) -2 -3 -2 -3 -4 -5 -6	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz able 9, 9~28V/m(385M evel 3, 2KV evel 4, 2KV/Line-Line evel 3, 10V evel 4, 30A/m	I 4, 8KV contac ~2.7GHz) 1Hz~5.78GHz	
MC	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE EMC EMISSION	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts Surge susceptit Conducted susc	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility ceptibility mmunity	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4	CISPR11) CISPR11) -2 -3 -2 -3 -4 -5 -6 -8	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz able 9, 9~28V/m(385Me evel 3, 2KV evel 4, 2KV/Line-Line evel 3, 10V	I 4, 8KV contact -2.7GHz) 1Hz~5.78GHz)	
МС	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE EMC EMISSION	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emiss Radiated emissi: Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts Surge susceptit Conducted susc Magnetic field in Voltage dip, inte	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility ceptibility mmunity	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4	CISPR11) CISPR11) -2 -3 -2 -3 -4 -5 -6 -8	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz able 9, 9~28V/m(385Me evel 3, 2KV evel 4, 2KV/Line-Line evel 3, 10V evel 4, 30A/m 00% dip 1 periods, 30% dip	I 4, 8KV contact -2.7GHz) 1Hz~5.78GHz)	
MC	ISOLATION LEVEL WITHSTAND VOLTAGE ISOLATION RESISTANCE EMC EMISSION EMC IMMUNITY	Design refer to I Primary-Second I/P-O/P: 4KVAC I/P-O/P:100M OI Parameter Conducted emissi Radiated emissi Harmonic curre Voltage flicker EN60601-1-2 Parameter ESD RF field suscep EFT bursts Surge susceptiti Conducted susc Magnetic field in Voltage dip, inte	EN60335-1 ary: 2xMOPP mms / 500VDC / 25° sion on nt tibility ceptibility mmunity erruption	C/70% RH Standard EN55011 (C EN55011 (C EN61000-3 EN61000-3 Standard EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 EN61000-4 CO)	CISPR11) CISPR11) -2 -3 -2 -3 -4 -5 -6 -8	T. C.	est Level / Note lass B lass B lass A est Level / Note evel 4, 15KV air; Leve evel 3, 10V/m(80MHz able 9, 9~28V/m(385Me evel 3, 2KV evel 4, 2KV/Line-Line evel 3, 10V evel 4, 30A/m 00% dip 1 periods, 30% dip	I 4, 8KV contact -2.7GHz) 1Hz~5.78GHz)	

- 3. Tolerance: includes set up tolerance, line regulation and load regulation.
- 4. Derating may be needed under low input voltages. Please check the derating curve for more details.
- 5. Touch current was measured from primary input to DC output.

NOTE

- 6. The ambient temperature derating of 5°C/1000m is needed for operating altitude greater than 2000m (6500ft).
- 7. The power supply is considered a component which will be installed into a final equipment. The final equipment must be re-confirmed that it still meets EMC directives. For guidance on how to perform these EMC tests, please refer to "EMI testing of component power supplies." (as available on http://www.meanwell.com)

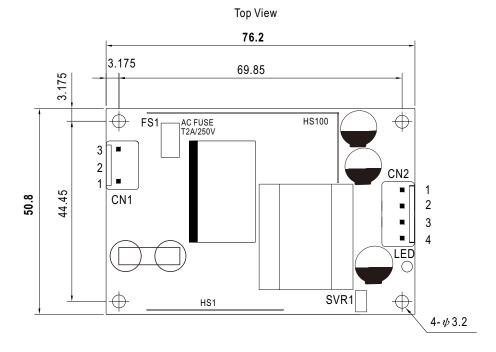


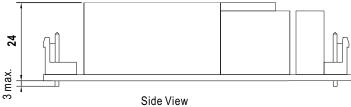




■ Mechanical Specification

Case No. Unit:mm





AC Input Connector (CN1): JST B3P-VH or equivalent

Pin No.	Assignment	Mating Housing	Terminal	
1	AC/N	IOTALID	107.0\(\(\)1.047.044	
2	No Pin	JST VHR or equivalent	JST SVH-21T-P1.1 or equivalent	
3	AC/L	or equivalent	or oquivalone	

DC Output Connector (CN2): JST B4P-VH or equivalent

Pin No.	Assignment	Mating Housing	Terminal
1	+V		
2	+V	JST VHR	JST SVH-21T-P1.1
3	-V	or equivalent	or equivalent
4	-V		

■ Installation Manual

Please refer to : http://www.meanwell.com/manual.html